

10V Drive Nch MOSFET

R6020ANZ

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Low input capacitance.
- 3) High ESD.

● Application

Switching

● Packaging specifications

Type	Package	Bulk
	Code	-
	Basic ordering unit (pieces)	360
R6020ANZ		○

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DSS}	600	V	
Gate-source voltage	V_{GSS}	± 30	V	
Drain current	Continuous	I_D^{*3}	± 20	A
	Pulsed	I_{DP}^{*1}	± 80	A
Source current (Body Diode)	Continuous	I_S^{*3}	20	A
	Pulsed	I_{SP}^{*1}	80	A
Avalanche current	I_{AS}^{*2}	10	A	
Avalanche energy	E_{AS}^{*2}	26.7	mJ	
Power dissipation	P_D^{*4}	120	W	
Channel temperature	T_{ch}	150	°C	
Range of storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 $L = 500 \mu H$, $V_{DD} = 50V$, $R_G = 25 \Omega$, $T_{ch} = 25^\circ C$

*3 Limited only by maximum channel temperature allowed.

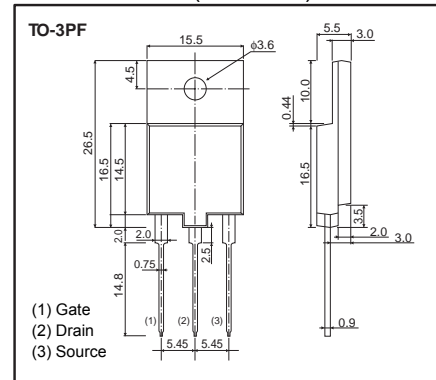
*4 $T_C = 25^\circ C$

● Thermal resistance

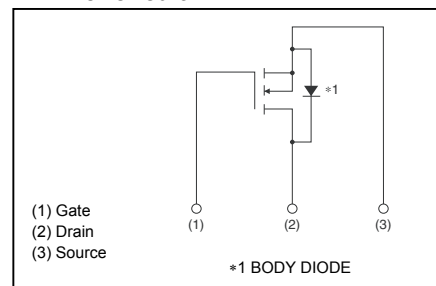
Parameter	Symbol	Limits	Unit
Channel to Case	$R_{th(ch-c)}^*$	1.04	°C / W

* $T_C = 25^\circ C$

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	±100	nA	$V_{GS}=\pm 30V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	600	-	-	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	-	-	100	μA	$V_{DS}=600V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	2.95	-	4.15	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	0.17	0.22	Ω	$I_D=10A, V_{GS}=10V$
Forward transfer admittance	$ Y_{fs} ^*$	7	-	-	S	$V_{DS}=10V, I_D=10A$
Input capacitance	C_{iss}	-	2040	-	pF	$V_{DS}=25V$
Output capacitance	C_{oss}	-	1660	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	-	70	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	40	-	ns	$V_{DD}\approx 300V, I_D=10A$
Rise time	t_r^*	-	60	-	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}^*$	-	230	-	ns	$R_L=30\Omega$
Fall time	t_f^*	-	70	-	ns	$R_G=10\Omega$
Total gate charge	Q_g^*	-	65	-	nC	$V_{DD}\approx 300V$
Gate-source charge	Q_{gs}^*	-	10	-	nC	$I_D=20A$
Gate-drain charge	Q_{gd}^*	-	25	-	nC	$V_{GS}=10V$

*Pulsed

● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}^*	-	-	1.5	V	$I_s=20A, V_{GS}=0V$

*Pulsed

●Electrical characteristic curves

Fig.1 Maximum Safe Operating Area

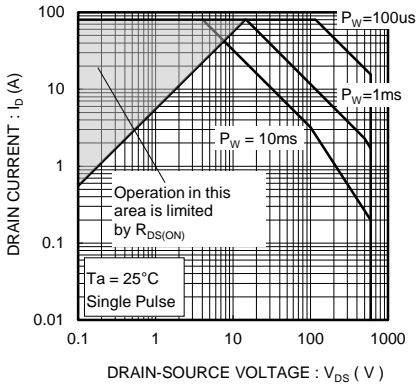


Fig.2: Typical output characteristics (I)

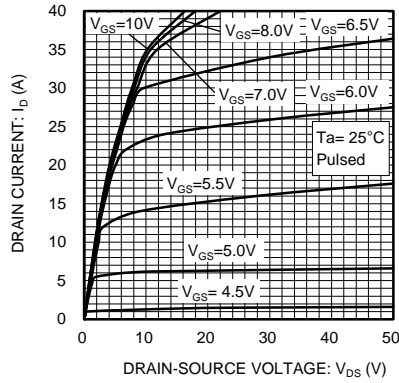


Fig.3: Typical output characteristics (II)

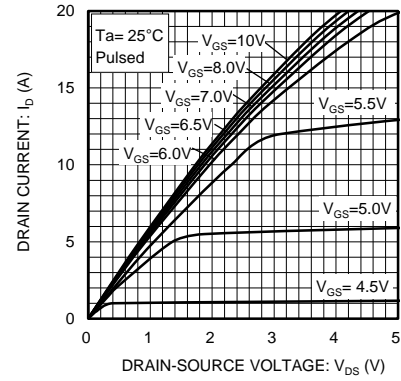


Fig.4 Typical Transfer Characteristics

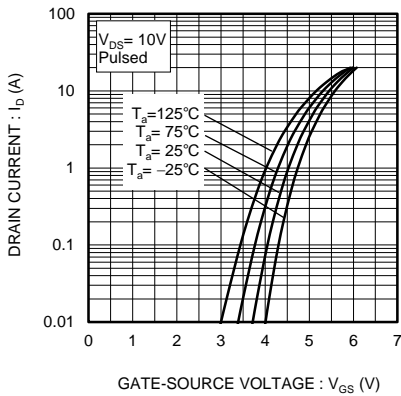


Fig.5 Gate Threshold Voltage vs. Channel Temperature

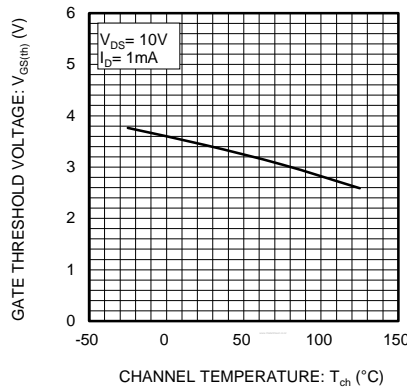


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

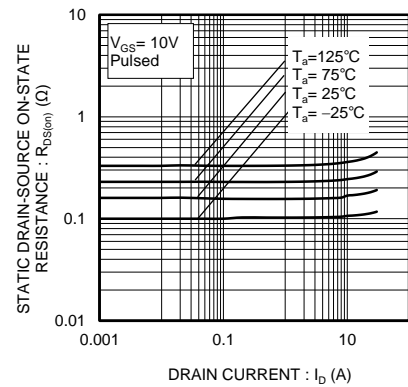


Fig.7 Static Drain-Source On-State Resistance vs. Gate Source Voltage

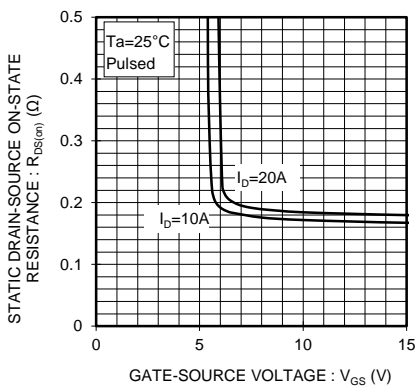


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

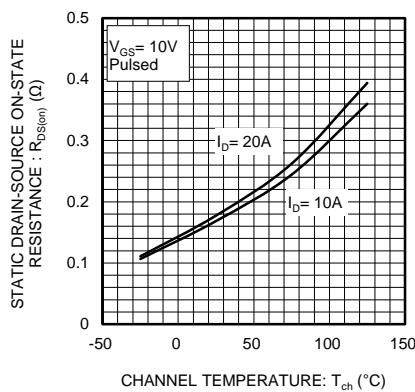


Fig.9 Forward Transfer Admittance vs. Drain Current

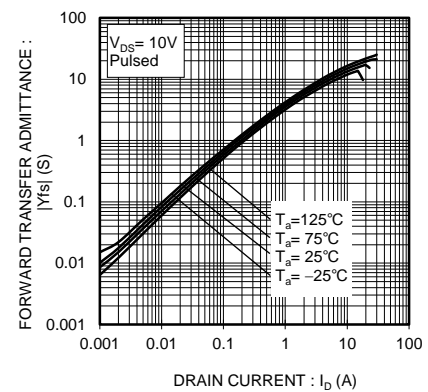


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

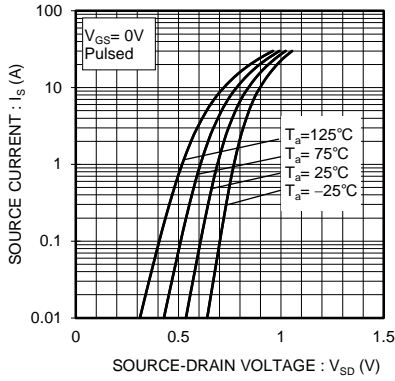


Fig.11 Typical Capacitance vs. Drain-Source Voltage

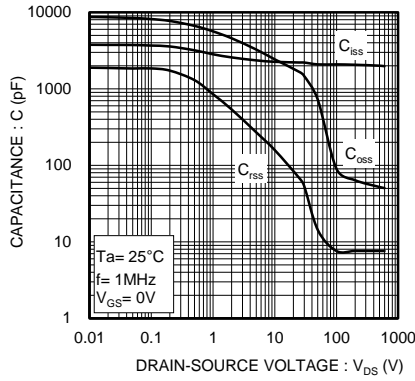


Fig.12 Dynamic Input Characteristics

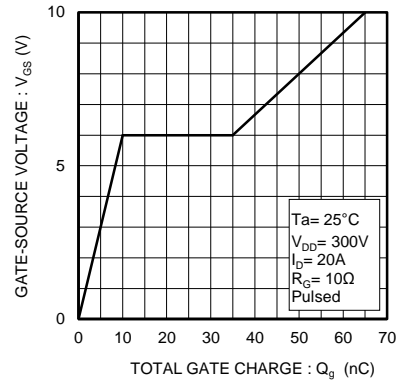


Fig.13 Reverse Recovery Time vs. Reverse Drain Current

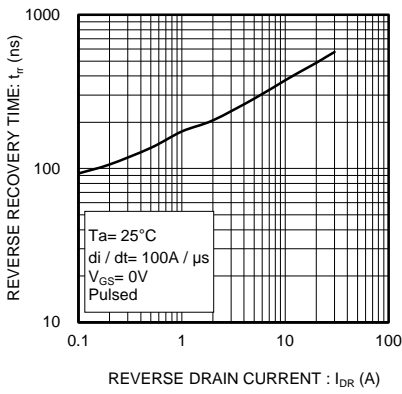


Fig.14 Switching Characteristics

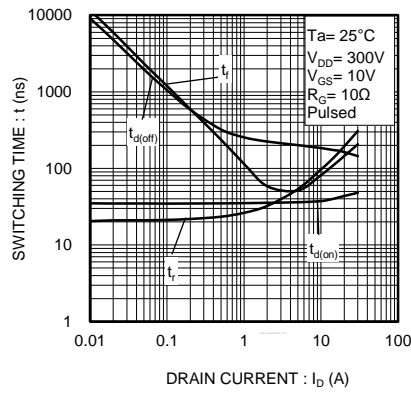
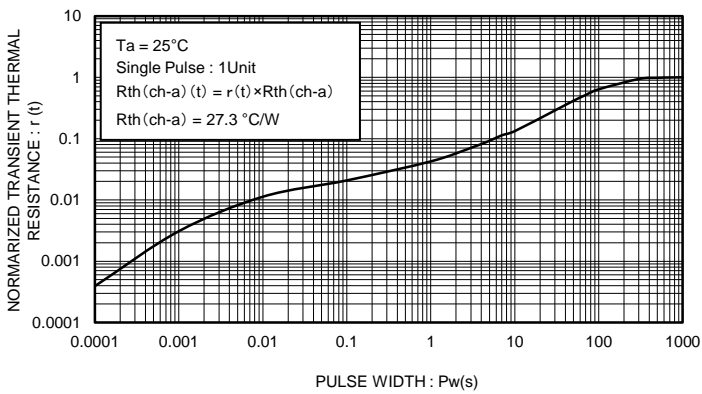


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width



● Measurement circuits

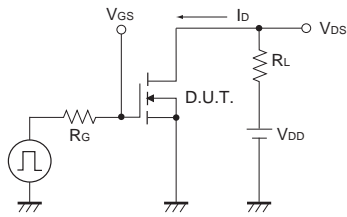


Fig.1-1 Switching Time Measurement Circuit

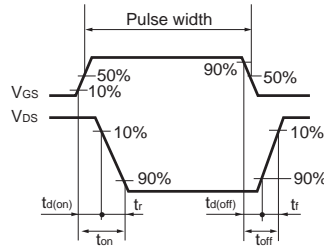


Fig.1-2 Switching Waveforms

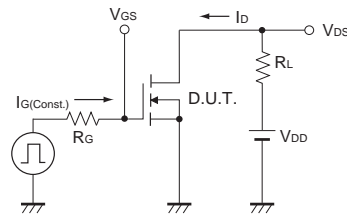


Fig.2-1 Gate Charge Measurement Circuit

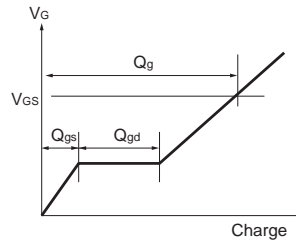


Fig.2-2 Gate Charge Waveform

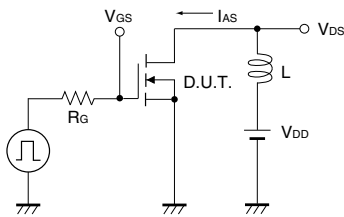


Fig.3-1 Avalanche Measurement Circuit

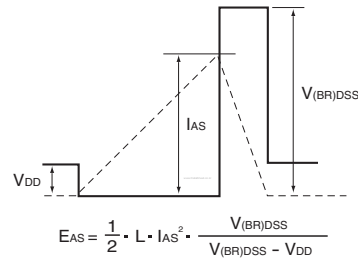


Fig.3-2 Avalanche Waveform

Notes

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